

TOSHIBA PHOTOCOUPLER PHOTO RELAY

TLP296G

TELECOMMUNICATION

DATA ACQUISITION

MEASUREMENT INSTRUMENTATION

The TOSHIBA TLP296G consists of gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a 8 lead DIP package (DIP8).

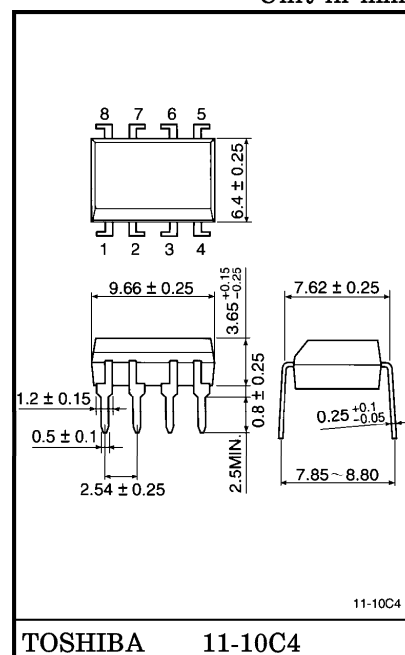
The TLP296G is a bi-directional switch which can replace mechanical relay in many applications.

- 8 PIN DIP (DIP8), 2 Channel Type (2-Form-A)
- Peak Off-State Voltage : 400 V (MIN.)
- Trigger LED Current : 5 mA (MAX.)
- On-State Current : 100 mA (MAX.)
- On-State Resistance : 30 Ω (MAX.)
- Isolation Voltage : 2500 V_{rms} (MIN.)
- Trigger LED Current (Ta = 25°C)

CLASSIFICATION	TRIGGER LED CURRENT (mA)		MARKING OF CLASSIFICATION
	@I _{ON} = 100 mA		
	MIN.	MAX.	
(IFT2)	—	2	T2
Standard	—	5	T2, blank

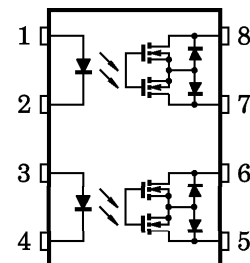
(*) : Ex. Rank IFT2 : TLP296G (IFT2)

Unit in mm



Weight : 0.54 g

PIN CONFIGURATION (Top view)



- 1, 3 : ANODE
- 2, 4 : CATHODE
- 5 : DRAIN D1
- 6 : DRAIN D2
- 7 : DRAIN D3
- 8 : DRAIN D4

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MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC			SYMBOL	RATING	UNIT
LED	Forward Current		I _F	50	mA
	Forward Current Derating (Ta ≥ 25°C)		ΔI _F / °C	−0.5	mA / °C
	Peak Forward Current (100 μs pulse, 100 pps)		I _{FP}	1	A
	Reverse Voltage		V _R	5	V
	Junction Temperature		T _j	125	°C
DETECTOR	Off-State Output Terminal Voltage		V _{OFF}	400	V
	On-State Current	Both Channel Note 1	I _{ON}	100	mA
		One Channel		120	
	On-State Current Derating (Ta ≥ 25°C)	Both Channel Note 1	ΔI _{ON} / °C	−1.0	mA / °C
		One Channel		−1.2	
	Junction Temperature		T _j	125	°C
	Storage Temperature Range		T _{stg}	−55~125	°C
Operating Temperature Range		T _{opr}	−20~85	°C	
Lead Soldering Temperature (10 s)			T _{sol}	260	°C
Isolation Voltage (AC, 1min., R.H. ≤ 60%)		Note 2	BV _S	2500	V _{rms}

(Note 1) : Two channels operating simultaneously.

(Note 2) : Device considered a two-terminal device : Pins 1, 2, 3 and 4 shorted together and Pins 5, 6, 7 and 8 shorted together.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V_{DD}	—	—	320	V
Forward Current	I_F	7.5	15	25	mA
On-State Current	I_{ON}	—	—	100	mA
Operating Temperature	T_{opr}	-20	—	80	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse Current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
DETECTOR	Off-State Current	I_{OFF}	$V_{OFF} = 400 \text{ V}$	—	—	1	μA
	Capacitance	C_{OFF}	$V = 0, f = 1 \text{ MHz}$	—	—	—	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I_{FT}	$I_{ON} = 100 \text{ mA}$	—	2	5	mA
On-State Resistance	R_{ON}	$I_{ON} = 100 \text{ mA}, I_F = 10 \text{ mA}$	—	20	30	Ω

ISOLATION CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation Resistance	R_S	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation Voltage	BV_S	AC, 1 minute	2500	—	—	V_{rms}
		AC, 1 second (in oil)	—	5000	—	
		DC, 1 minute (in oil)	—	5000	—	Vdc

SWITCHING CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Turn-on Time	t_{ON}	$R_L = 200 \Omega$ (Note 1)	—	—	4	ms
Turn-off Time	t_{OFF}	$V_{DD} = 20 \text{ V}, I_F = 10 \text{ mA}$	—	—	4	

(Note 1) : SWITCHING TIME TEST CIRCUIT

